

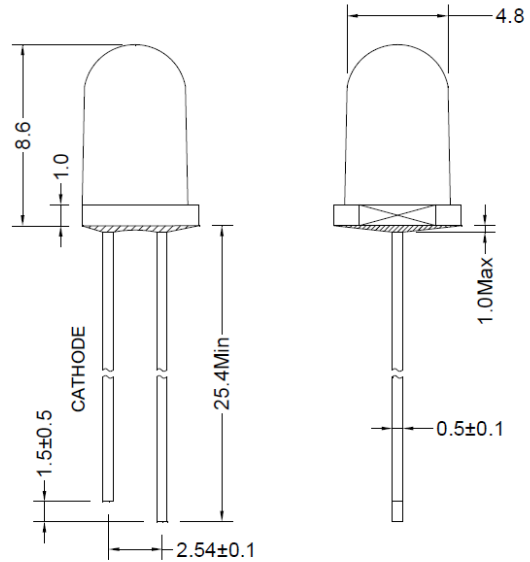
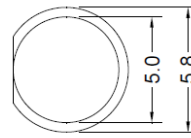


➤ **Features/特征:**

- Single color/单色
- High bright output/高亮度输出
- Low power consumption/低功耗
- High reliability and long life/
可靠性高、寿命长

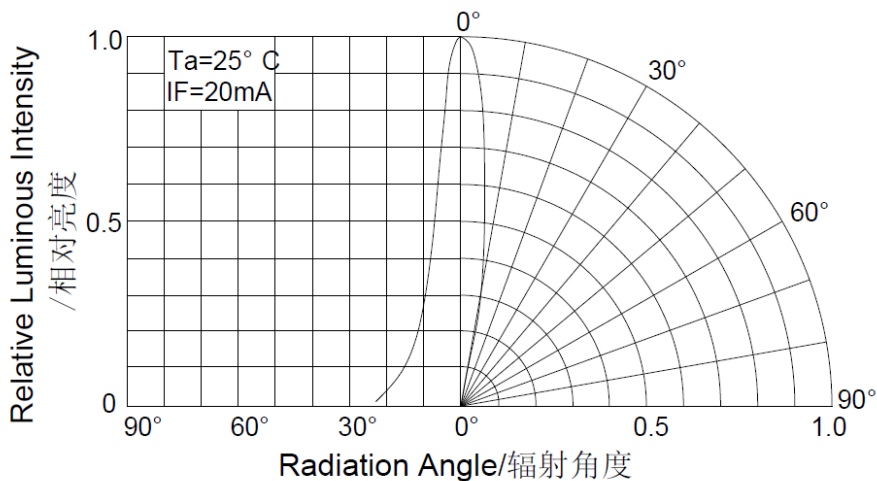
➤ **Descriptions/描述:**

- Dice material/芯片材质: AlGaInP
- Emitting Color/发光颜色:
Super Bright Red/ 高亮度红色
- Device Outline/产品外形:
Φ5mm Round Type/ 5mm 圆形
- Lens Type 胶体颜色:
Water Clear/ 无色透明



1. All dimensions are millimeters/单位: mm.
2. Tolerance is +/-0.25mm unless otherwise noted/
没有标注的公差均为±0.25mm.

➤ **Directivity/指向特性:**



➤ **Absolute maximum ratings/极限参数 (Ta = 25°C)**

Parameter 参数	Symbol 符号	Test Condition 测试条件	Values 数值		Unit 单位
			Min.	Max.	
Reverse Voltage 反向电压	V _R	I _R = 30 μA	5	----	V
Forward Current 正向工作电流	I _F	----	----	30	mA
Power Dissipation 损耗功率	P _d	----	----	75	mW
Pulse Current 正向峰值电流	I _{peak}	Duty=0.1mS, 1kHz	----	100	mA
Operating Temperature 工作温度范围	T _{opr}	----	-40	+85	°C
Storage Temperature 储存温度范围	T _{str}	----	-40	+100	°C
Soldering Temperature 焊接温度	T _{sd}	t ≤ 3sec, 2mm from case	----	260	°C

➤ **Electrical and optical characteristics/光电参数 (Ta = 25°C)**

Parameter 参数	Symbol 符号	Test Condition 测试条件	Values 数值			Unit 单位
			Min.	Typ.	Max.	
Forward Voltage 正向电压	V _F	I _F =20mA	1.8	2.1	2.5	V
Reverse Current 反向电流	I _R	V _R =5V	----	----	30	μA
Dominate Wavelength 主波长	λ _d	I _F =20mA	----	624	----	nm
Peak Wavelength 峰值波长	λ _p	I _F =20mA	----	632	----	nm
Spectral Line half-width 半波长宽度	Δλ	I _F =20mA	----	17	----	nm
Luminous Intensity 发光强度	I _v	I _F =20mA	----	16000	----	mcd
Viewing Angle 指向角度	2θ _{1/2}	I _F =20mA	----	15	----	deg.

➤ **Luminous Intensity Bins/亮度等级分档 (Ta = 25°C)**

Unit:mcd

Bin	ZA	ZB
Min	12000	16000
Max	16000	23500

➤ **Forward Current Bins/电压等级分档 (Ta = 25°C)**

Unit:V

Bin	V2	V3
Min	1.8	2.0
Max	2.0	2.2



➤ Typical electrical/optical characteristic curves/光电特性曲线:

Fig.1 正向电流 Vs. 正向电压

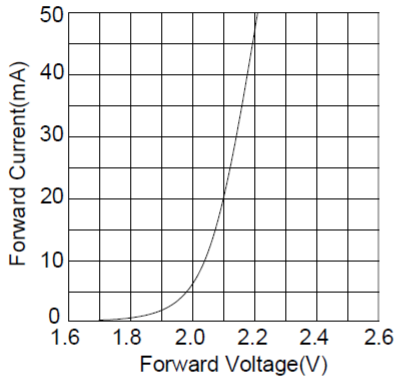


Fig.2 相对亮度 Vs. 正向电流

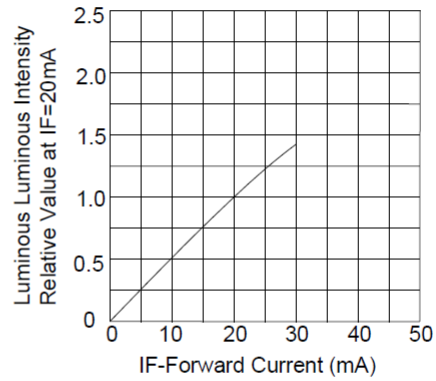


Fig.3 正向电流 Vs. 环境温度

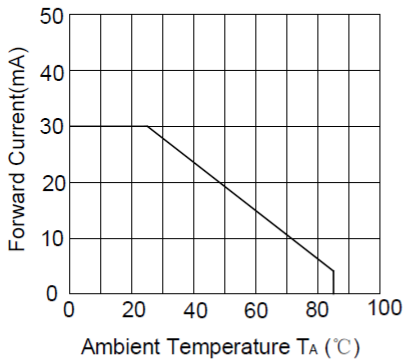


Fig.4 相对亮度 Vs. 环境温度

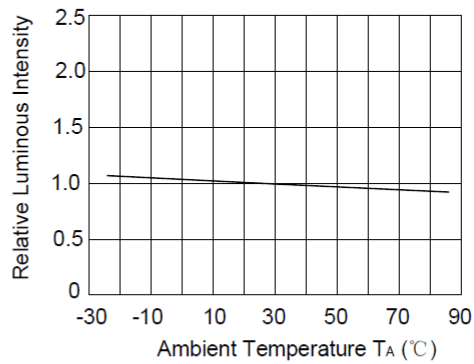


Fig.5 相对亮度 Vs. 波长

